# 2SC3052-T150

FOR LOW FREQUENCY AMPLIFY APPLICATION SILICON NPN EPITAXIAL TYPE

AEC-Q101 Compliance

## **DESCRIPTION**

2SC3052 is a mini package resin sealed silicon NPN epitaxial transistor,

It is designed for low frequency voltage application.

## **FEATURE**

- Small collector to emitter saturation voltage.

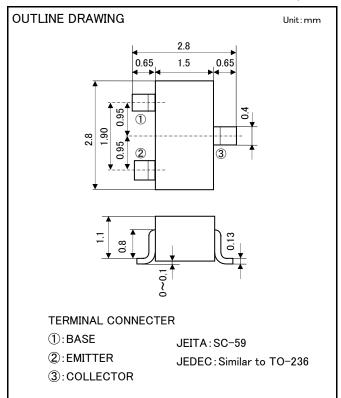
  VCE(sat)=0.3V max(@IC=100mA/IB=10mA)
- Excellent linearity of DC forward current gain.
- Super mini package for easy mounting

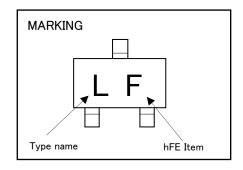
## **APPLICATION**

For Hybrid IC, Small type machine low frequency voltage amplify application.

## MAXIMUM RATINGS (Ta=25°C)

Parameter	Symbol	Ratings	Unit
Collector to Base voltage	V <sub>CBO</sub>	50	٧
Emitter to Base voltage	V <sub>EBO</sub>	6	٧
Collector to Emitter voltage	V <sub>CEO</sub>	50	٧
Collector current	I o	200	mA
Collector dissipation	P <sub>c</sub>	200	mW
Junction temperature	T <sub>j</sub>	+150	°C
Storage temperature	$T_{stg}$	-55 <b>~</b> +150	°C





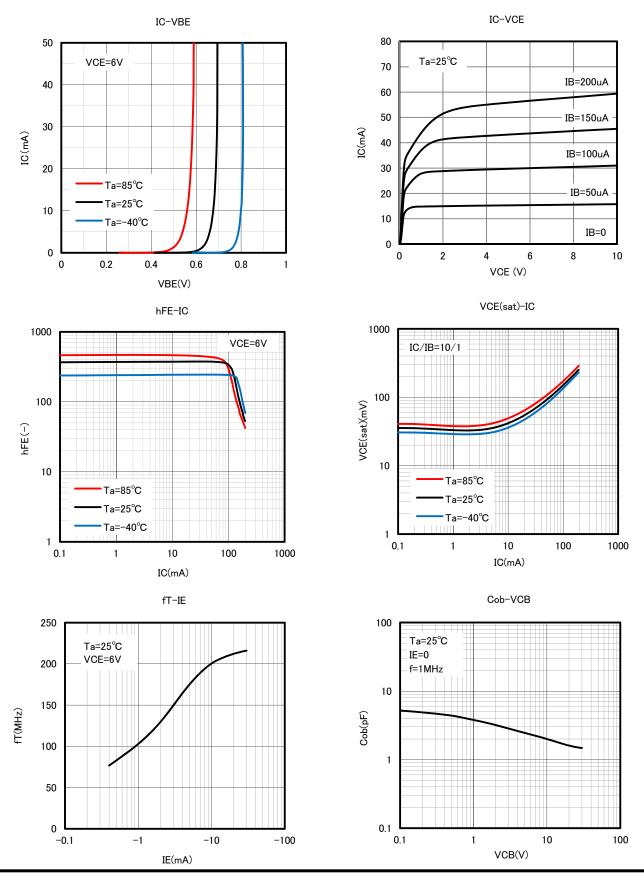
## ELECTRICAL CHARACTERISTICS(Ta=25°C)

Downston	0 1 1	bol Test conditions	Limits			1124
Parameter	Symbol		Min	Тур	Max	Unit
C to E breakdown voltage	V(BR)ceo	I <sub>C</sub> =100 μ A ,R <sub>BE</sub> =∞	50	-	-	٧
Collector cut off current	ICBO	V <sub>CB</sub> =50V, I <sub>E</sub> =0mA	-	-	0.1	μΑ
Emitter cut off current	IEBO	V <sub>EB</sub> =6V, I <sub>C</sub> =0mA	-	-	0.1	μΑ
DC forward current gain ※	hFE	V <sub>CE</sub> =6V, I <sub>C</sub> =1mA	150	-	500	-
DC forward current gain	hFE	$V_{CE}$ =6V, $I_{C}$ =0.1mA	100	-	-	-
C to E Saturation voltage	VCE(sat)	I <sub>C</sub> =100mA ,I <sub>B</sub> =10mA	-	-	0.3	٧
B to E Saturation voltage	VBE(sat)	I <sub>C</sub> =100mA ,I <sub>B</sub> =10mA	-	-	1.0	٧
Gain bandwidth product	fT	V <sub>CE</sub> =6V, I <sub>E</sub> =-10mA	-	200	-	MHz
Collector output capacitance	Cob	V <sub>CB</sub> =6V, I <sub>E</sub> =0,f=1MHz	-	2.5	-	pF
Noise figure	NF	$V_{CE}=6V, I_{E}=-0.1$ mA,f=1kHz,RG=2k $\Omega$	_	_	15	dB

X) It shows hFE classification at right table.

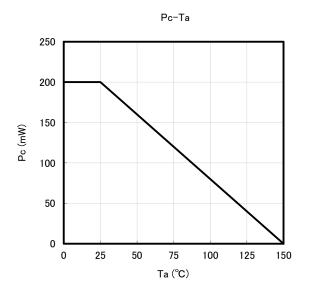
Item	E	F
hFE Item	150~300	250~500

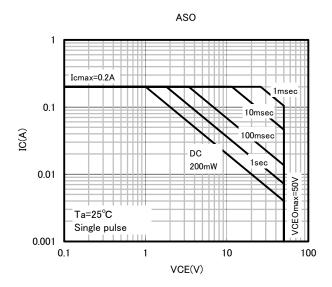
## TYPICAL CHARACTERISTICS



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